## PATENT ASSIGNMENT

Electronic Version v1.1 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

# **CONVEYING PARTY DATA**

Name	Execution Date
Chih-Chung Wang	08/22/2011
Wei-Lun Hsu	08/22/2011
Shan-Shi Huang	08/22/2011
Ke-Feng Lin	08/22/2011
Te-Yuan Wu	08/22/2011

#### RECEIVING PARTY DATA

Name:	UNITED MICROELECTRONICS CORP.
Street Address:	No.3, Li-Hsin Road 2, Science-Based Industrial Park
City:	Hsin-Chu City
State/Country:	TAIWAN

### PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	13216276

#### CORRESPONDENCE DATA

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ATTORNEY DOCKET NUMBER:	NAUP1321USA
NAME OF SUBMITTER:	SHELLEY KUO

Total Attachments: 3 source=1188901#page1.tif source=1188901#page2.tif

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**PATENT REEL: 026796 FRAME: 0085** 

# ASSIGNMENT OF INVENTION

In consideration of the payment by ASSIGNEE to ASSIGNOR of the sum of One Dollar (\$1.00), the receipt of which is hereby acknowledged, and for other good and valuable consideration.

	•			
N	Name:	Chih-Chung Wang	_Nationality:	TW
Ŋ	Name:	Wei-Lun Hsu	Nationality:	TW
ľ	Name:	Shan-Shi Huang	_Nationality:	TW
ì	Name:	Ke-Feng Lin	_Nationality:	TW
]	Name:	Te-Yuan Wu	_Nationality:	TW
Hereby sells, assigns and transfers to  ASSIGNEE(S):				
LOUL	GIIDE(S)			
-	Name:	UNITED MICROELECTRONICS CORP.		
	Address:	No.3, Li-Hsin Road 2, Science-Based Industrial Park, Hsin-Chu City 300, Taiwan, R.O.C.		

Assignment, Page 1 of 3

F#NPO-P0002E-US1

ASSIGNOR(S) (Inventors):

**PATENT REEL: 026796 FRAME: 0086**  and the successors and assignees of the ASSIGNEE the entire right, title, and interest in and to any and all improvements which are disclosed in the invention entitled:

"HIGH VOLTAGE METAL-OXIDE-SEMICONDUCTOR TRANSISTOR DEVICE AND METHOD OF FABRICATING THE SAME"

Which	is found in:			
(a)	<u>+</u> U.S. p	atent application exec	cuted on even date	
(b)	U.S. p	atent application exec	cuted on	
(c)	U.S. a	oplication serial no		
(d)	patent	10.	issued	
(e)	Interna	tional application no.	•	

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F#NPO-P0002E-US1

**PATENT REEL: 026796 FRAME: 0087** 

NPO#NAU-P1321-USA:0 CUST#UMCD-2010-0568

DSC0-100U003962

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and, in and to, all Letters Patent to be obtained for said invention by the above application or any continuations, continuation-in-part, divisions, renewals, substitutes, or extensions thereof, and as to Letters Patent any reissue or re-examination thereof

ASSIGNOR hereby covenants that no assignment, sale, agreement or encumbrance has been or will be made or entered into which would conflict with this assignment;

ASSIGNOR further covenants that ASSIGNEE will, upon its request, be provided promptly with all pertinent facts and documents relating to said invention and said Letters Patent and legal equivalents as may be known and accessible to ASSIGNOR and will testify as to the same in any interference, litigation or proceeding related thereto and will promptly execute and deliver to ASSIGNEE or its legal representatives any and all papers, instruments or affidavits required to apply for, obtain, maintain, issue and enforce said application, said invention and said Letters Patent and said equivalents thereof which may be necessary or desirable to carry out the proposes thereof.

IN WITNESS WHEREOF, We have hereunto set hand and seal this AUG 2 2 2011 (Date of signing). (请将明人物必要带上列目期 )

(Type name of inventor)	Signature of INVENTOR
Chih-Chung Wang	Chih-Chung, Wang
Wei-Lun Hsu	Wei-Lun Hsy
Shan-Shi Huang	Shu-shi Huang
Ke-Feng Lin	6 - Fung Lin
Te-Yuan Wu	To - Ynon Win

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NPO#NAU-P1321-USA:0 CUST#UMCD-2010-0568 F#NPO-P0002E-US1 DSC0-100U003962

**PATENT** 

REEL: 026796 FRAME: 0088